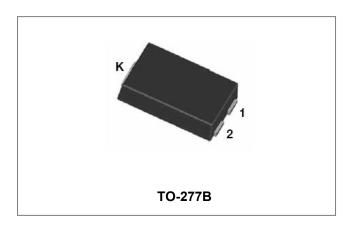


Technical Data Data Sheet N1709 Rev. A

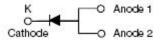




ST1060S SCHOTTKY RECTIFIER



Circuit Diagram



Features

- 150°C T_J operation
- Center tap configuration
- Ultra low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- "-A" is an AEC-Q101 qualified device
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	60	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T _c =80°C, rectangular wave form	10	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse, T _c = 25 °C	275	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V_{F1}	@ 10A, Pulse, T _J = 25 °C	-	0.60	V
Reverse Current*	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}\text{C}$	-	0.36	mA
	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 125 ^{\circ}\text{C}$	20	-	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C f_{SIG} = 1MHz$	850	-	pF

^{*} Pulse width < 300 μ s, duty cycle < 2%



Technical Data Data Sheet N1709 Rev. A



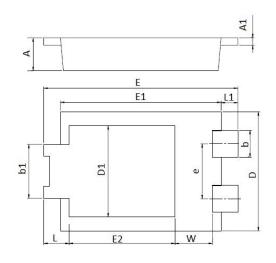


Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Ambient (Note 2)	$R_{ heta JA}$	DC operation	110	°C/W
Typical Thermal Resistance Junction to Case (Note1)	R ₀ JC	DC operation	10	°C/W
Approximate Weight	wt	-	0.08	g

Notes: 1. Mounted on an FR4 PCB, single-sided copper, with 100cm₂ copper pad area.

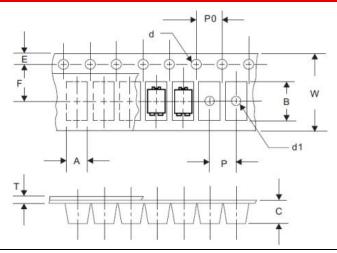
Mechanical Dimensions TO-277B





SYMBOL	Millin	Millimeters		Inches	
OTHIBOL	Min.	Max.	Min.	Max.	
Α	0.95	1.25	0.037	0.049	
A1	0.20	0.30	0.008	0.012	
b	0.85	0.95	0.033	0.037	
b1	1.70	1.90	0.067	0.075	
D	3.88	4.08	0.153	0.161	
D1	2.90	3.20	0.114	0.126	
е	1.74	1.94	0.069	0.076	
E	6.30	6.70	0.248	0.264	
E1	5.28	5.48	0.208	0.216	
E2	3.40	3.70	0.134	0.146	
L	0.70	1.00	0.028	0.039	
L1	0.41	0.71	0.016	0.028	
W	1.10	1.40	0.043	0.055	

Carrier Tape Specification TO-277B



SYMBOL	Millimeters		
	Min.	Max.	
Α	4.28	4.48	
В	6.80	7.10	
С	1.30	1.50	
d	1.40	1.60	
d1	-	1.50	
Е	1.65	1.85	
F	5.40	5.60	
Р	7.90	8.10	
P0	3.90	4.10	
Т	0.24	0.44	
W	11.70	12.30	

- China Germany Korea Singapore United States •
- http://www.smc-diodes.com sales@ smc-diodes.com •

^{2.} Mounted on an FR4 PCB, single-sided copper, mini pad.



Technical Data Data Sheet N1709 Rev. A





Ordering Information

Device	Package	Shipping
ST1060S	TO-277B(Pb-Free)	5000pcs/ reel
ST1060STR	TO-277B(Pb-Free)	5000pcs/ reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



ST = Device Type
10 = Forward Current (10A)
60 = Reverse Voltage (60V)
S = Package type
YY = Year
WW = Week
L = Lot Number

Where XXXXX is YYWWL

Cautions: Molding resin

Epoxy resin UL:94V-0

DISCLAIMER:

- 1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC Diode Solutions sales department for the latest version of the datasheet(s).
- 2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.
- 3- In no event shall SMC Diode Solutions be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC Diode Solution assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.
- 4- In no event shall SMC Diode Solutions be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.
- 5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC Diode Solutions.
- 6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC Diode Solutions.
- 7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations..